HIGH VOLTAGE SURFACE MOUNT SWITCHING DIODE ARRAY

Features

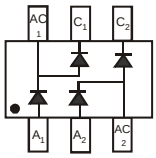
- Two Series Diode Circuits Connect to Form Full Wave Bridge
- Fast Switching Speed
- High Conductance
- High Reverse Breakdown Voltage Rating
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Matte Tin Finish Annealed over Copper Leadframe (Lead-Free Plating). Solderable per MIL-STD-202, Method 208 e3
- Polarity: See Diagram
- Weight: 0.016 grams (Approximate)

SOT-26

TOP VIEW



TOP VIEW

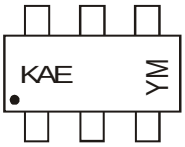
Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
MMBD3004BRM-7	SOT-26	3000/Tape & Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



KAE = Product Type Marking Code
YM = Date Code Marking
Y =Year ex: B = 2014
M = Month ex: 9 = September

Date Code Key

Year	2006	2007	…	2011	2012	2013	2014	2015	2016	2017	2018	2019
Code	T	U	…	Y	Z	A	B	C	D	E	F	G

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	350	V
Working Peak Reverse Voltage DC Blocking Voltage	V_{RWM} V_R	300	V
RMS Reverse Voltage	$V_{R(RMS)}$	212	V
Forward Continuous Current (Note 5)	I_F	225	mA
Peak Repetitive Forward Current (Note 5)	I_{FRM}	625	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0µs @ t = 1.0s	I_{FSM}	4.0 1.0	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	350	mW
Thermal Resistance Junction to Ambient Air (Note 5)	$R_{\theta JA}$	357	°C/W
Operating and Storage Temperature Range	T_J , T_{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	$V_{(BR)R}$	350	—	—	V	I_R = 150µA
Forward Voltage	V_F	—	0.78 0.93 1.03	0.87 1.0 1.25	V	I_F = 20mA I_F = 100mA I_F = 200mA
Reverse Current (Note 6)	I_R	— —	30 35	100 100	nA µA	V_R = 240V V_R = 240V, T_J = +150°C
Total Capacitance	C_T	—	1.0	5.0	pF	V_R = 0V, f = 1.0MHz
Reverse Recovery Time	t_{rr}	—	—	50	ns	I_F = I_R = 30mA, I_{rr} = 3.0mA, R_L = 100Ω

Notes: 5. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
6. Short duration pulse test used to minimize self-heating effect.

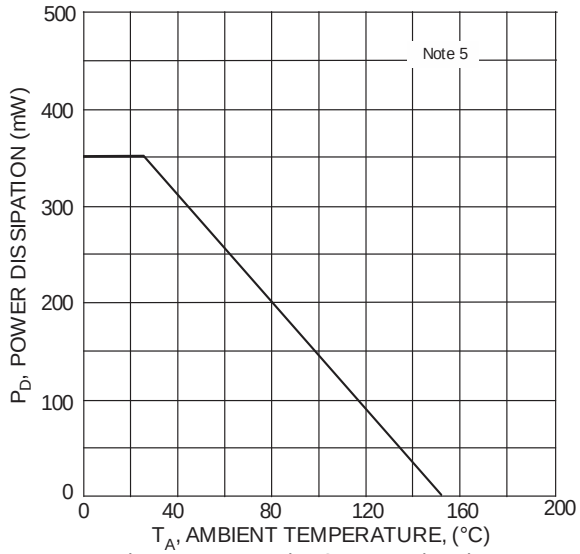


Fig. 1 Power Derating Curve, Total Package

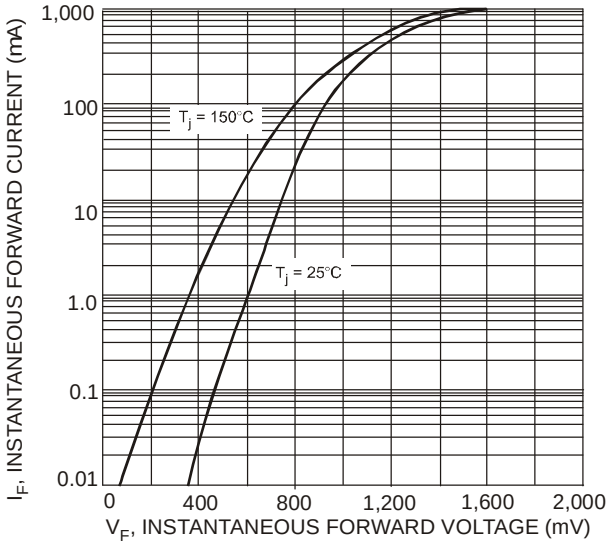


Fig. 2 Typical Forward Characteristics, Per Element

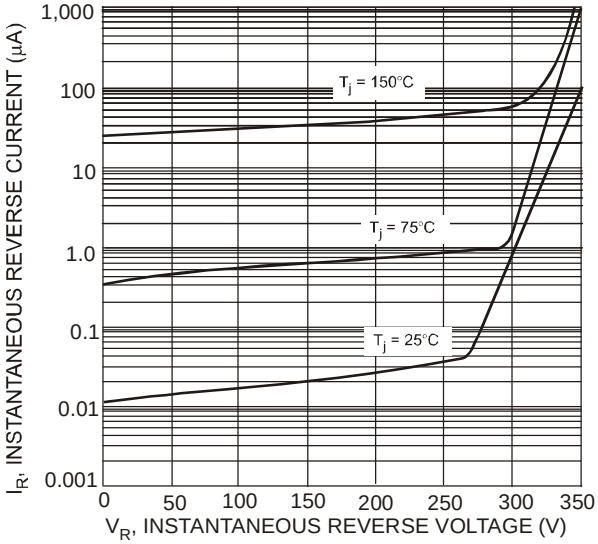


Fig. 3 Typical Reverse Characteristics, Per Element

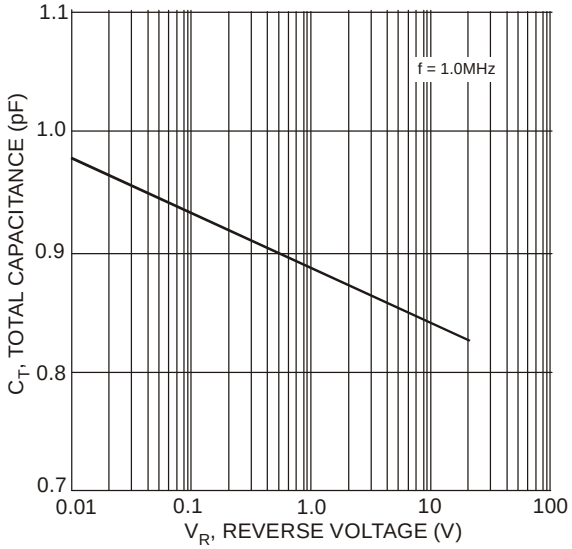
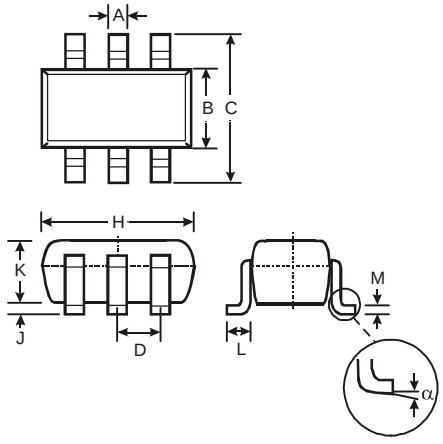


Fig. 4 Total Capacitance vs. Reverse Voltage, Per Element

Package Outline Dimensions

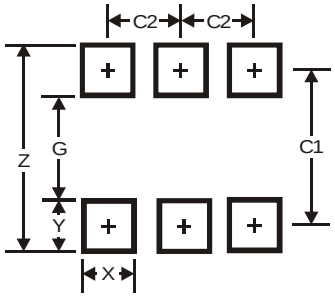
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26			
Dim	**Min**	**Max**	**Typ**
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95